#### Building High-Performance Smartphones via Non-Volatile Memory: The Swap Approach

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http://nvm-swap.bitbucket.org/

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#### **Outline**

- Background
  - Performance and Energy
  - Swapping
- NVM-Swap: NVM based swapping
  - Copy-on-Write Swap-in (COWS)
  - WL Algorithm: Heap-Wear
- Evaluation
- Conclusion

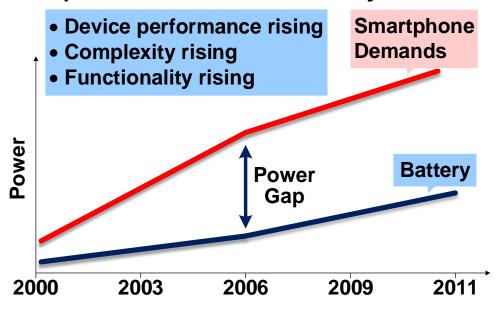
#### **Background** — Performance

Large DRAM is required for high performance smartphones



#### Background — Energy

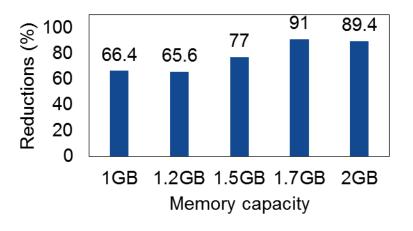
- More DRAM, more energy consumption
  - DRAM consumes up to 34.5% of overall energy
- Rise more pressure on battery lifetime



- [1] Rice, A etc., Decomposing power measurements for mobile devices, IEEE PerCom 2011.
- [2] A. Carroll etc., An analysis of power consumption in a smartphone, USENIX ATC 2010.
- [3] Avneesh Agrawal, "Trends in Wireless Communications", available at http://www.ieee infocom.org/2010/docs/Infocom2010\_keynote.pdf.

## Background — Swapping

- Write inactive pages to swap device
  - Extend main memory space



Reduce around 66% ~ 91% of process terminations.

- Swapping is not practical in smartphones
  - Poor performance of smartphone internal flash
  - Limited program/erase cycles of flash memory

## Why not use flash base swapping

Swapping is disabled in smartphones

	SLC NAND flash	MLC NAND flash	DRAM
Endurance	100,000 P/E cycles	30,000 P/E cycles	>10 <sup>16</sup>
Read page	25us	<b>75us</b>	~ns
Program page	200us	1600us	~ns
Erase block	700us	5ms	-

- Process will be terminated directly if no memory space left
  - Bad user experience

[1] Micron, "1Gb x8, x16: NADN Flash Memory Features" MT29F1G08ABBDAH4 data sheet, 2010 [2] Micron, "128Gb 256GB, 512Gb Async/Sync Enterprise NAND Features" MT29E128G08CECAB data sheet, 2010

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## **Emerging NVM technology**

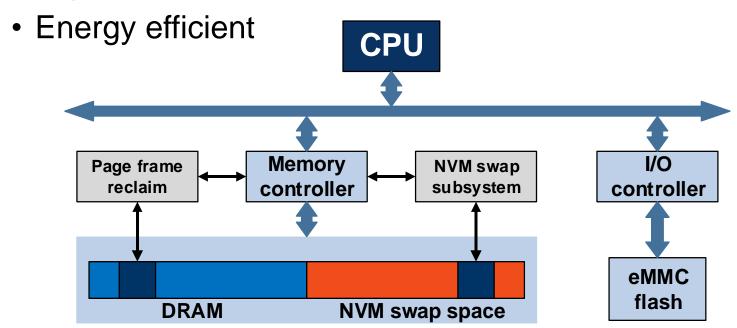
- Emerging Non-Volatile Memory (NVM)
  - Byte-addressable, high density, low standby power etc.
  - Near DRAM performance

	PRAM	RRAM	STT-RAM	DRAM
Endurance	10 <sup>8</sup>	10 <sup>8</sup>	>10 <sup>15</sup>	>10 <sup>16</sup>
Read time (ns)	20–50	10–50	2–20	30
Write / Erase time (ns)	50 / 120	10–50	2–20	15
Cell size (F <sup>2</sup> )	6–12	6–10	6–20	6-10
High voltage required	1.5-3V	1.5-3V	<1.5V	3V
Refresh operation	No	No	No	Yes

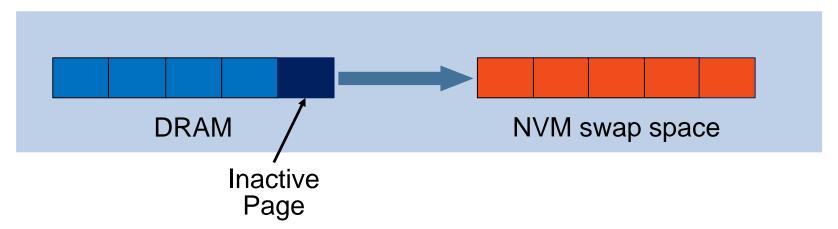
Alexander Driskill-Smith, Latest Advances and Future Prospects of STT-RAM, NVMW 2010

## NVM-Swap: NVM based swapping

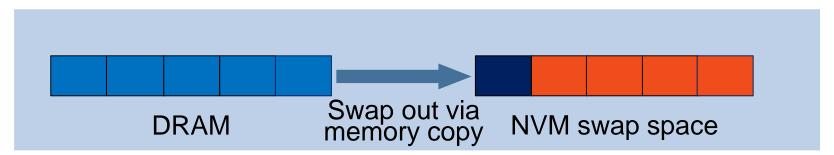
- Revisiting swapping in smartphones with emerging NVM
  - NVM is attached to the memory bus and used as swap area
  - High-performance



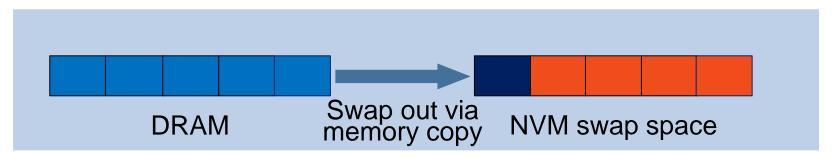
Swap out:



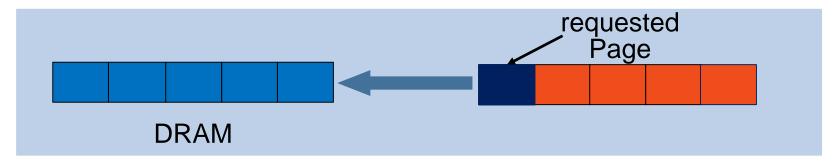
Swap out:



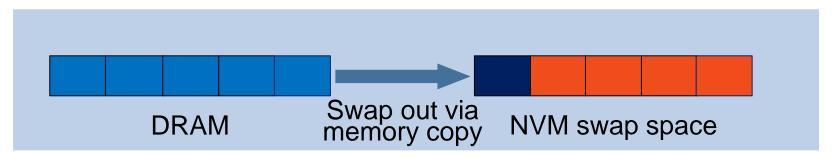
Swap out:



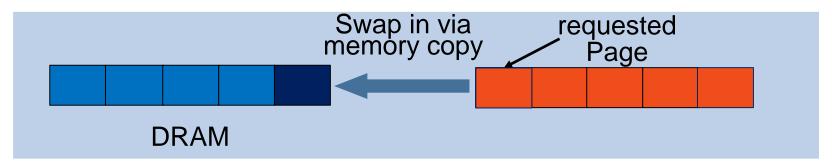
#### Swap in:



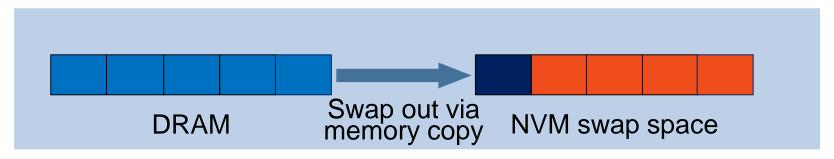
Swap out:



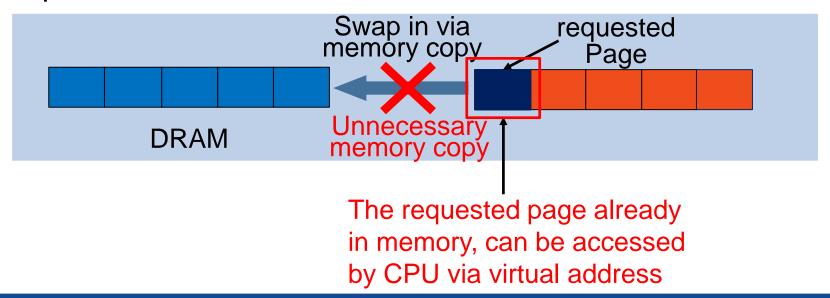
#### Swap in:

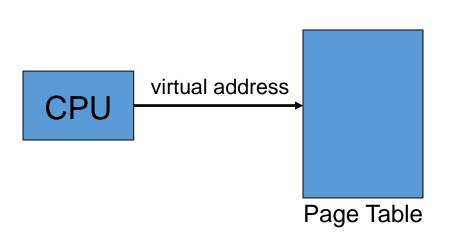


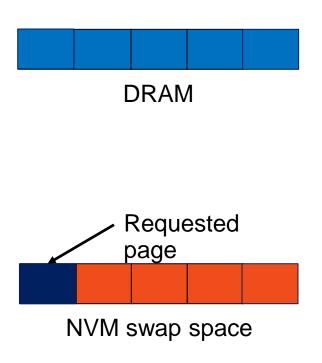
Swap out:

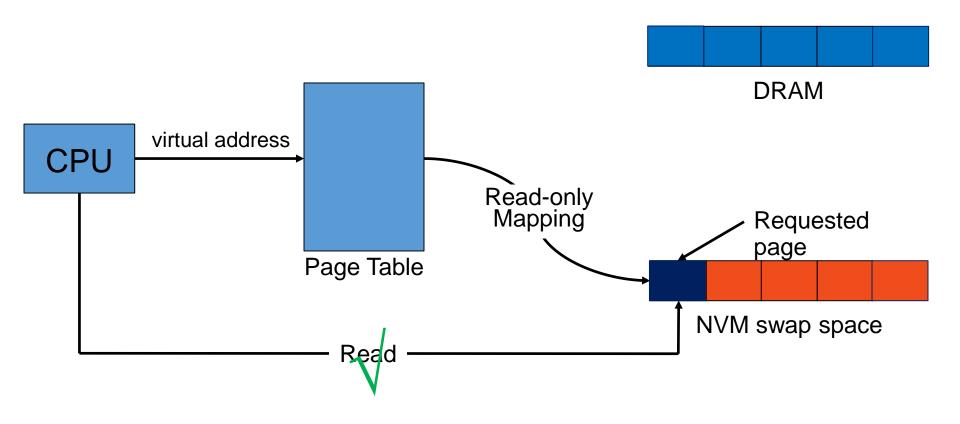


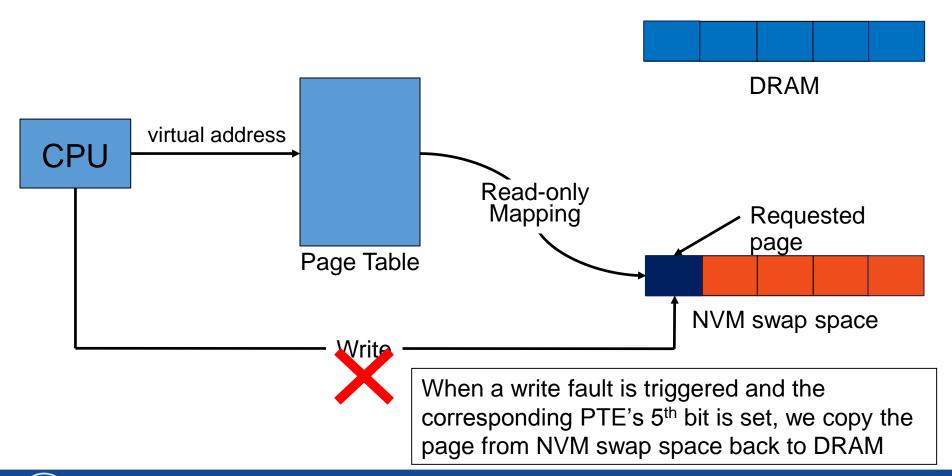
#### Swap in:

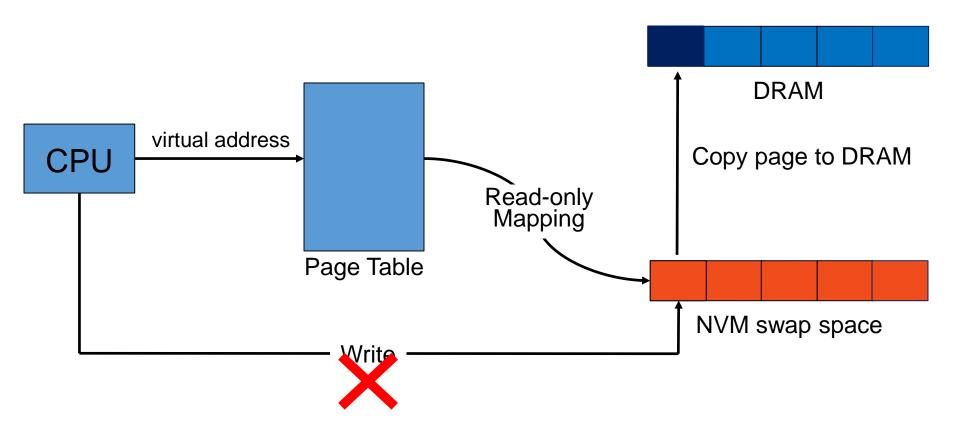


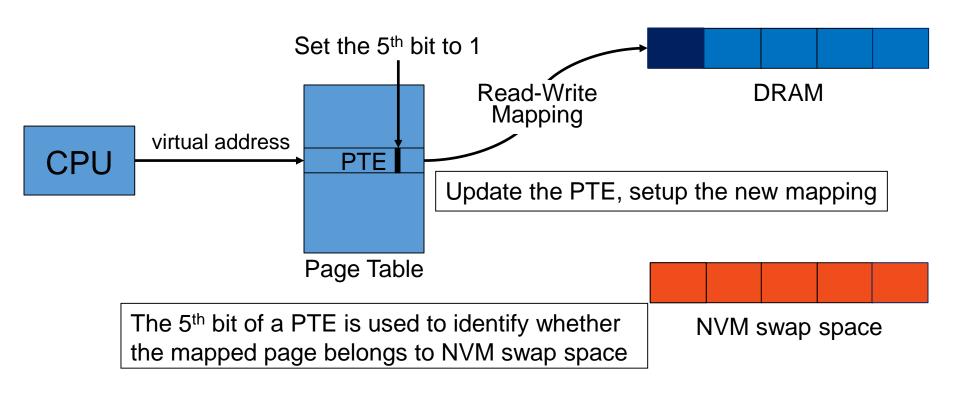


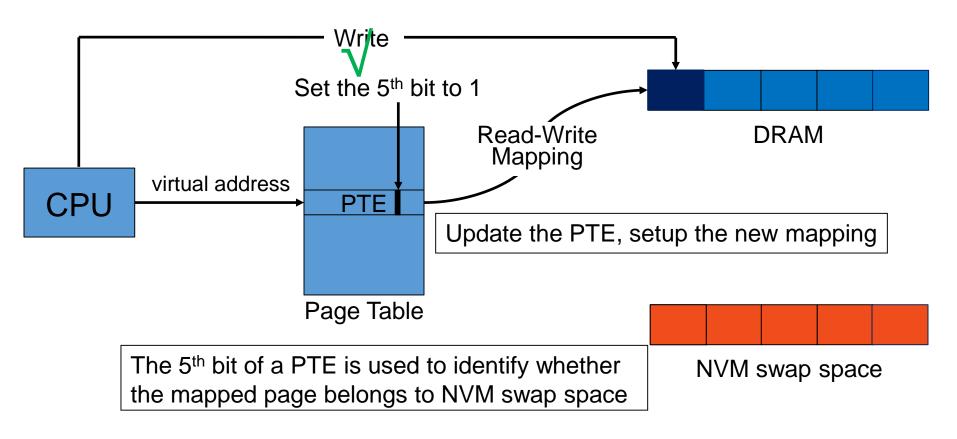






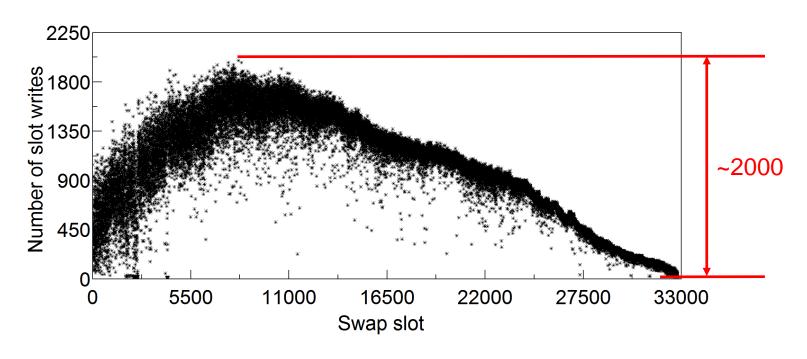






#### **NVM-Swap endurance problem**

Unbalance writes in NVM swap area

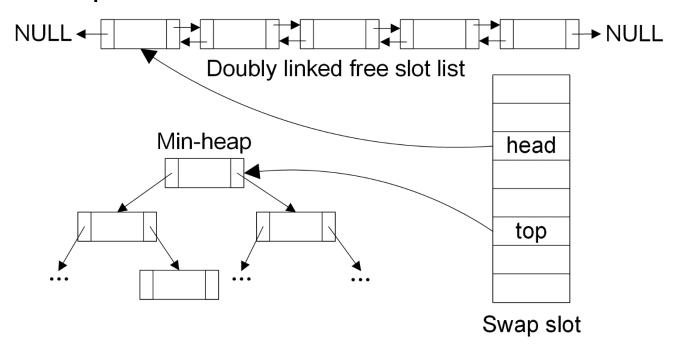


- Endurance issue of NVM
  - E.g. PCM cell only has  $10^8 \sim 10^9$  programming cycles
  - Most NVMs are vulnerable to unbalance writes

#### Heap-Wear: NVM-Swap Wear leveling

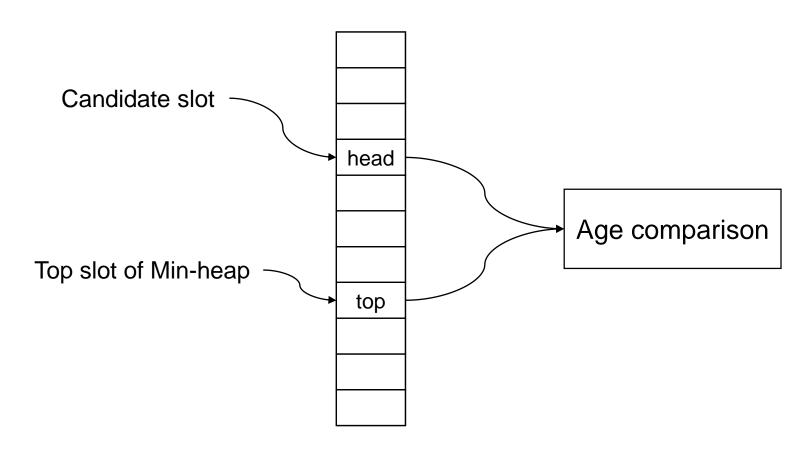
#### ■ Data structure

- Age counter for each swap slot
- Doubly linked list
- Min-heap

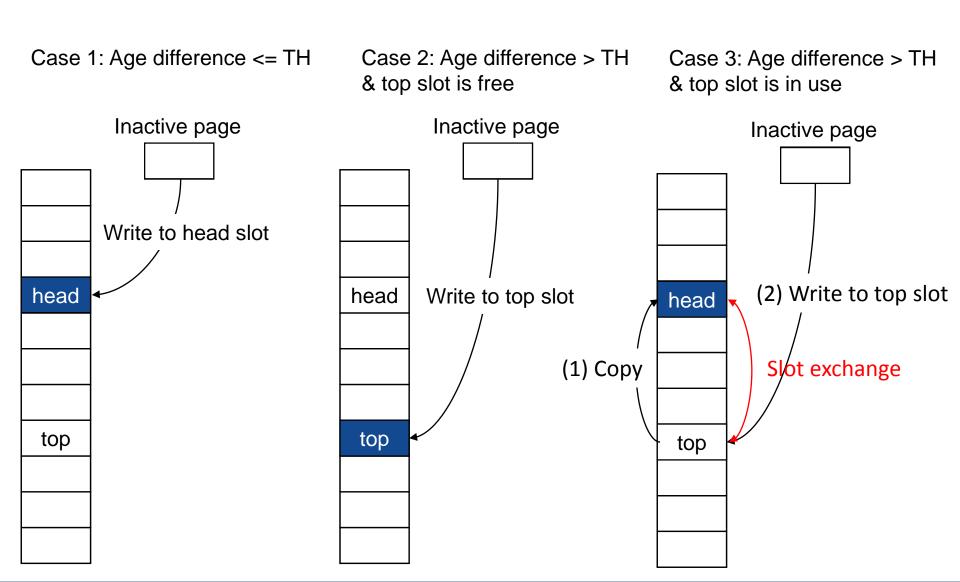


#### Heap-Wear: NVM-Swap Wear leveling

- Age comparison
  - Compare the age of head slot with the top slot



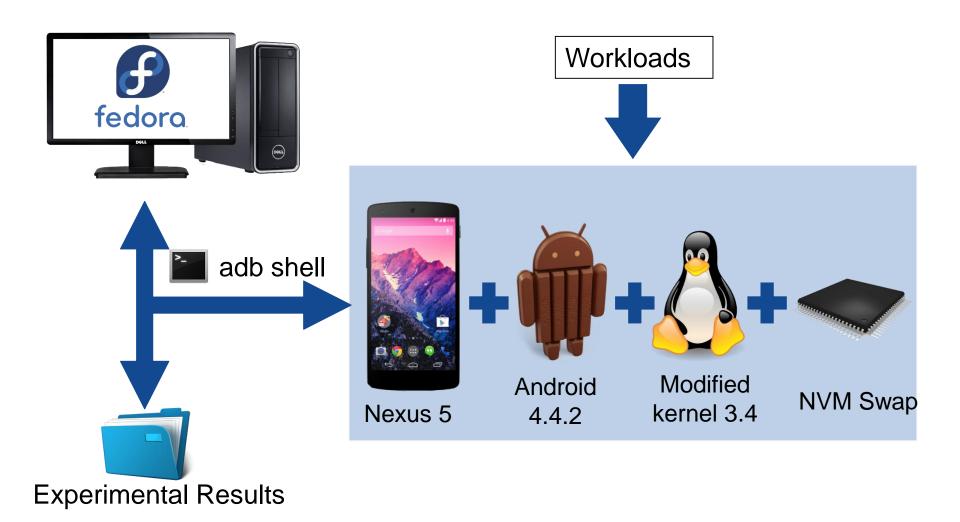
## Heap-Wear: NVM-Swap Wear leveling



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## Evaluation — Experimental setup



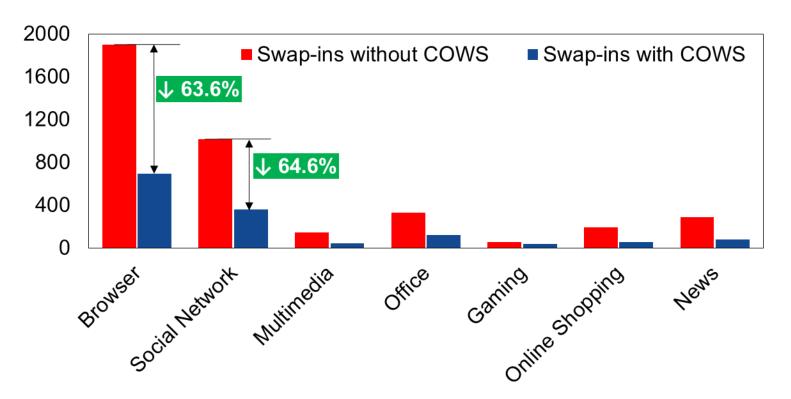
#### **Evaluation** — Metrics

Metrics	Description
Number of memory copy operations	<ul><li>Measure the effectiveness of COWS</li><li>Run various of applications</li></ul>
Wear-leveling	<ul><li>Evaluate the effectiveness of Heap-Wear</li><li>Write 128GB data to swap space in total</li></ul>
Application launch time	<ul><li>Important performance metric for smartphone users</li><li>Use customized applications</li></ul>

# **Evaluation** — Applications

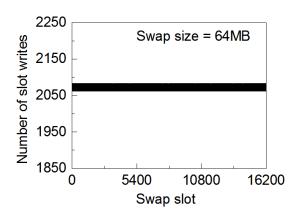
Category	Applications
Browser	
Social network	
Multimedia	You Tube
Office	Office
Gaming	Google Play Games
Shopping	amazon ebay Taobao.com
News	NEWS Flipboard TED engadget  NETEASE WWW.163.com

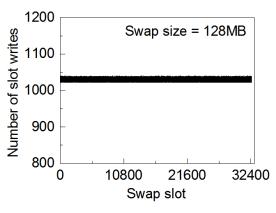
- Memory copy reduction
  - COWS can help reduce around 40% ~ 75% of swap-ins



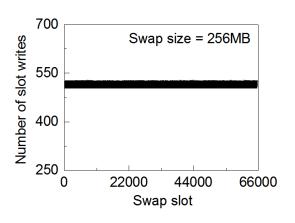
Comparison of Number of memory copy operations

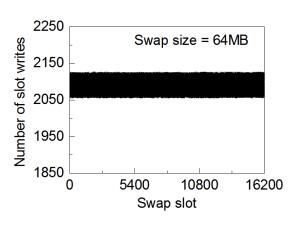
#### Wear-leveling

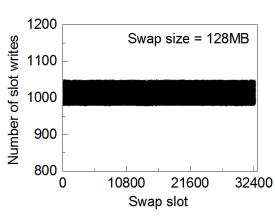


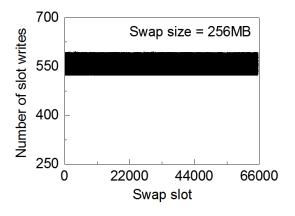


Threshold = 16



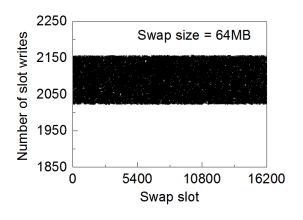


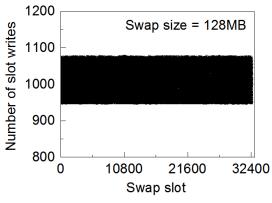




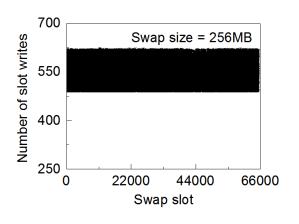
Threshold = 64

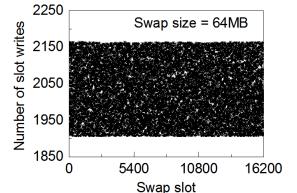
#### ■ Wear-leveling

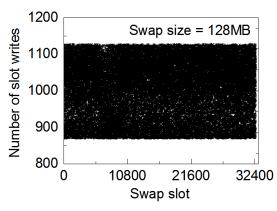


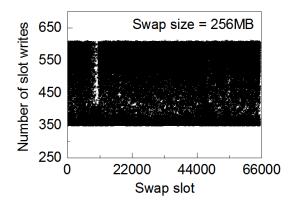


Threshold = 128







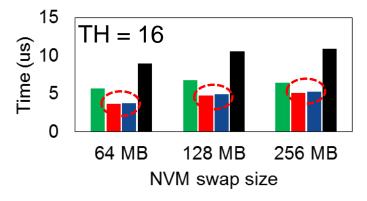


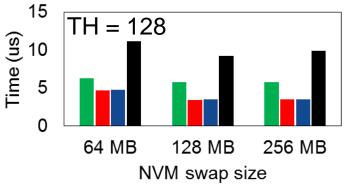
Threshold = 256

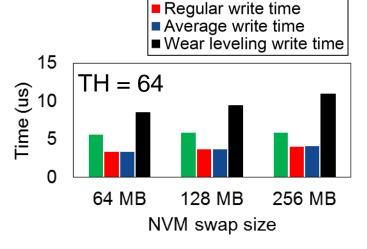
Wear-leveling overhead

Distribute the writes evenly across the swap space with

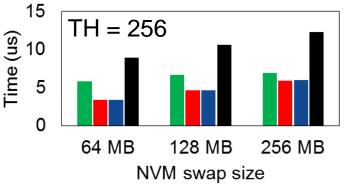
negligible overhead



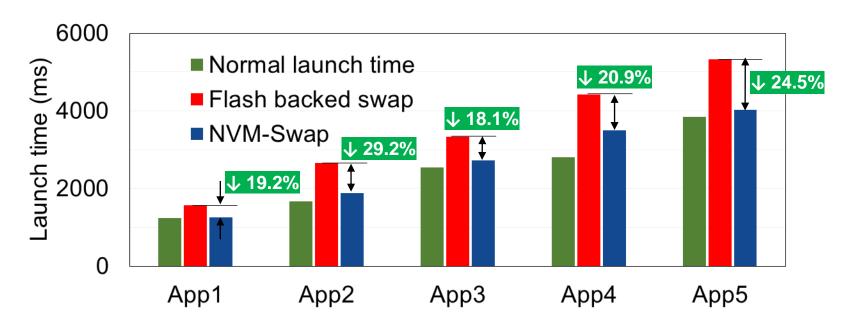




■ Read time



- Application launch time
  - NVM-Swap is more than 20% faster on average compared to Flash backed swap



App1-5 simulate application launch by loading a file of size 10MB to 30MB (5MB increment)

#### Conclusion

- We revisited swapping in smartphones and proposed NVM-Swap to build high-performance smartphones
- COWS: Remove unnecessary memory copy operations
  - More than 50% memory copy operations reduction
- Heap-Wear: WL algorithm for NVM swap space
  - Distribute writes evenly across whole swap space with negligible overhead
- Improve user experience
  - Compared to flash-based swap, application launch time is reduced more than 20% with the help of NVM-Swap

# Thank you! Question?

http://nvm-swap.bitbucket.org/